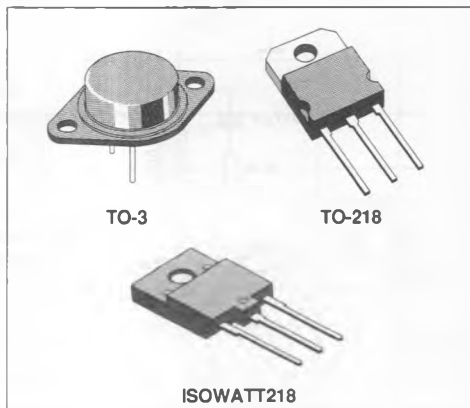


## HORIZONTAL TVC DEFLECTION

- HIGH VOLTAGE
- HIGH POWER
- HIGH SWITCHING SPEED
- GOOD STABILITY
- CONSUMER
- POWER SUPPLY
- TV COLOR HORIZONTAL DEFLECTION

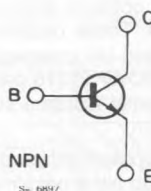


### DESCRIPTION

The BU208/A, BU508/A and the BU508FI/AFI are silicon multiepitaxial mesa NPN transistors.

They are respectively in Jedec TO-3 metal case in TO-218 plastic case and in ISOWATT218 fully isolated package.

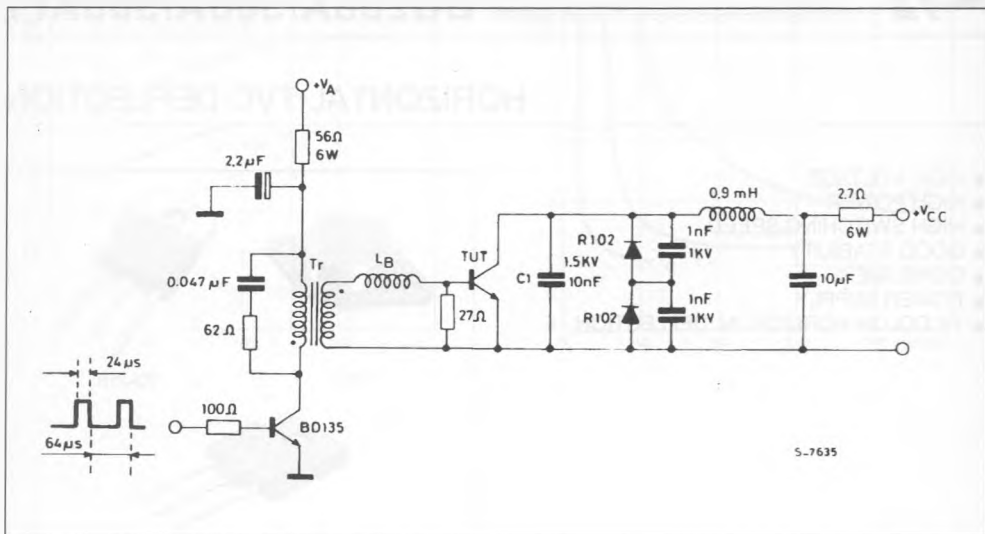
### INTERNAL SCHEMATIC DIAGRAM



### ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value			Unit
$V_{CES}$	Collector-emitter Voltage ( $V_{BE} = 0$ )	1500			V
$V_{CEO}$	Collector-emitter Voltage ( $I_B = 0$ )	700			V
$V_{EBO}$	Emitter-base Voltage ( $I_C = 0$ )	10			V
$I_C$	Collector Current	8			A
$I_{CM}$	Collector Peak Current	15			A
		<b>TO-3</b>	<b>TO-218</b>	<b>ISOWATT218</b>	
$P_{Tot}$	Total Dissipation at $T_c = 25^\circ\text{C}$	150	125	60	W
$T_{stg}$	Storage Temperature	- 65 to 175	- 65 to 150	- 65 to 150	$^\circ\text{C}$
$T_j$	Max. Operating Junction Temperature	175	150	150	$^\circ\text{C}$

Figure 1 : Switching Times Test Circuit on Inductive Load.



**ISOWATT218 PACKAGE CHARACTERISTICS AND APPLICATION**

ISOWATT218 is fully isolated to 4000V dc. Its thermal impedance, given in the data sheet, is optimised to give efficient thermal conduction together with excellent electrical isolation. The structure of the case ensures optimum distances between the pins and heatsink. These distances are in agreement with VDE and UL creepage and clearance standards. The ISOWATT218 package eliminates the need for external isolation so reducing fixing hardware.

The package is supplied with leads longer than the standard TO-218 to allow easy mounting on pcbs. Accurate moulding techniques used in manufacture

assures consistent heat spreader-to-heatsink capacitance.

ISOWATT218 thermal performance is equivalent to that of the standard part, mounted with a 0.1 mm mica washer.

The thermally conductive plastic has a higher breakdown rating and is less fragile than mica or plastic sheets.

Power derating for ISOWATT218 packages is determined by :

$$P_D = \frac{T_J - T_C}{R_{th}}$$

**THERMAL IMPEDANCE OF ISOWATT218 PACKAGE**

Figure 2 illustrates the elements contributing to the thermal resistance of a transistor heatsink assembly, using ISOWATT218 package.

The total thermal resistance  $R_{th(tot)}$  is the sum of each of these elements.

The transient thermal impedance,  $Z_{th}$  for different pulse durations can be estimated as follows :

- 1-For a short duration power pulse of less than 1ms :  
 $Z_{th} < R_{thJ-C}$
- 2-For an intermediate power pulse of 5ms seconds :  
 $Z_{th} = R_{thJ-C}$

3-For long power pulses of the order of 500ms seconds or greater :

$$Z_{th} = R_{thJ-C} + R_{thC-HS} + R_{thHS-amb}$$

It is often possible to discern these areas on transient thermal impedance curves.

Figure 2.



**THERMAL DATA**

			<b>TO-3</b>	<b>TO-218</b>	<b>ISOWATT218</b>	
$R_{thj-case}$	Thermal Resistance Junction-case	Max	1	1	2.08	°C/W

**ELECTRICAL CHARACTERISTICS** ( $T_{case} = 25^{\circ}C$  unless otherwise specified)

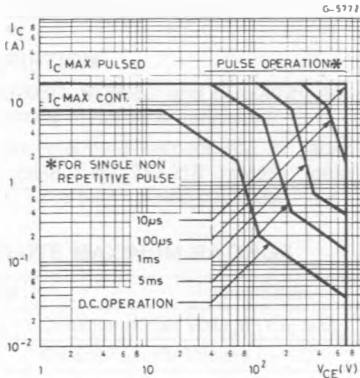
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$I_{CES}$	Collector Cutoff Current ( $V_{BE} = 0$ )	$V_{CE} = V_{CES}$ $T_C = 125^{\circ}C$ $V_{CE} = V_{CES}$			1 2	mA mA
$I_{EBO}$	Emitter Cutoff Current ( $I_C = 0$ )	$V_{EB} = 5V$			100	$\mu A$
$V_{CE(sus)^*}$	Collector Emitter Sustaining Voltage	$I_C = 100mA$	700			V
$V_{EBO}$	Emitter-base Voltage ( $I_C = 0$ )	$I_E = 10mA$	10			V
$V_{CE(sat)^*}$	Collector-emitter Saturation Voltage	$I_C = 4.5A$ $I_B = 2A$ for <b>BU208A/508A508AFI</b> for <b>BU208/508508FI</b>			1 5	V V
$V_{BE(sat)^*}$	Base-emitter Saturation Voltage	$I_C = 4.5A$ $I_B = 2A$			1.3	V
$f_T$	Transition Frequency	$I_C = 0.1A$ $V_{CE} = 5V$ $f = 5MHz$		7		MHz

**INDUCTIVE LOAD**

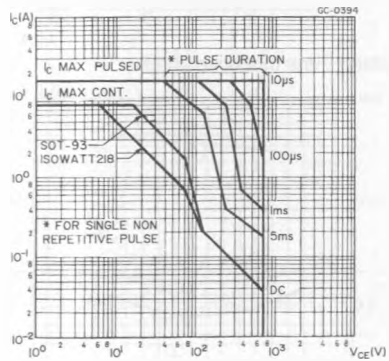
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit.
$t_s$	Storage Time	$I_C = 4.5A$ $h_{FE} = 2.5$ $V_{CC} = 140V$		7		$\mu s$
$t_f$	Fall Time	$L_C = 0.9mH$ $L_B = 3\mu H$		0.55		$\mu s$

\* Pulsed : pulse duration = 300  $\mu s$ , duty cycle = 1.5 %.

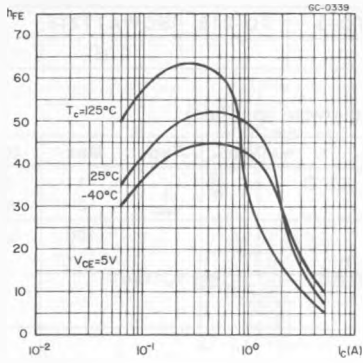
**Safe Operating Area (TO-3).**



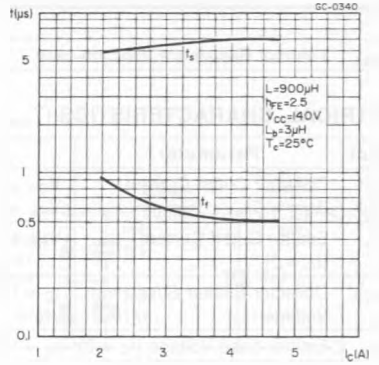
**Safe Operating Area (TO-218/ISOWATT218).**



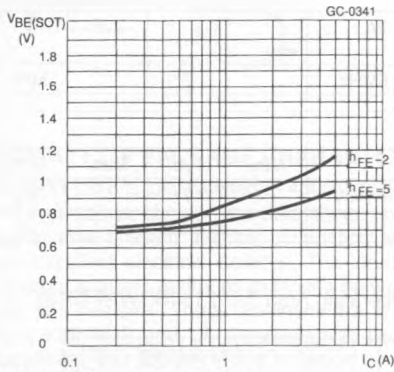
DC Current Gain.



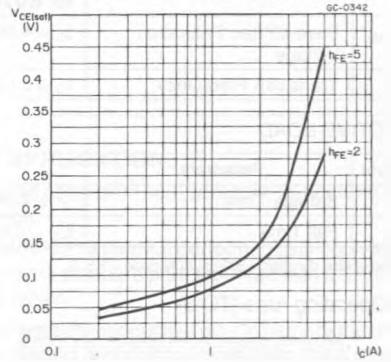
Switching Time Inductive Load.



Base-emitter Saturation Voltage.



Collector-emitter Saturation Voltage.



Switching Time Inductive Load.

